TOSHIBA CMOS DIGITAL INTEGRATED CIRCUIT SILICON MONOLITHIC

TC74HCT688AP, TC74HCT688AF

8-BIT EQUALITY COMPARATOR

The TC74HCT688A is a high speed CMOS 8 — BIT EQUALITY COMPARATOR fabricated with silicon gate C²MOS technology.

It achieves the high speed operation similar to equivalent LSTTL while maintaining the CMOS low power dissipation. This device may be used as a level converter for interfacing TTL or NMOS to High Speed CMOS. The inputs are compatible with TTL, NMOS and CMOS output voltage leveles.

The TC74HCT688A compares two 8-bit binary or BCD words applied inputs P0~P7, and inputs Q0~Q7, and indictes whether or not they are equal.

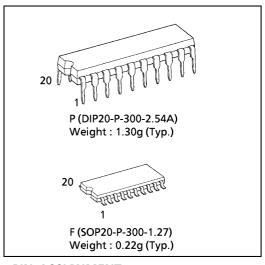
A signal active low enable is provided to facilitate cascading of several package to compare of words greater than 8 bits. All inputs are equipped with protection circuits against atatic discharge or transent excess volgtage.

FEATURES:

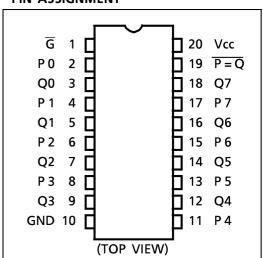
- High Speed······ t_{pd} = 17ns(typ.) at V_{CC} = 5V
- Low Power Dissipation $I_{CC} = 4\mu A(Max.)$ at $Ta = 25^{\circ}C$
- Compatible with TTL outputs····· $V_{IH} = 2.0V$ (Min.)

$$V_{II} = 0.8V(Max.)$$

- Output Drive Capability 10 LSTTL Loads
- Symmetrical Output Impedance | I_{OH} | = I_{OL} = 4mA(Min.)
- Balanced Propagation Delays ····· t_{oLH} ≃ t_{oHL}
- Pin and Function Compatible with 74LS688



PIN ASSIGNMENT



TRUTH TABLE

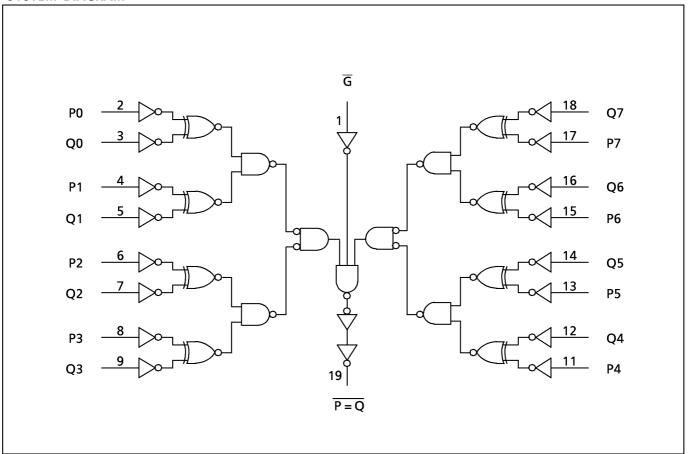
| INP | OUTPUT | |
|-------|--------|-------------------------------|
| P,Q | G | $\overline{P} = \overline{Q}$ |
| P = Q | L | L |
| P≠Q | L | Н |
| Х | Н | Н |

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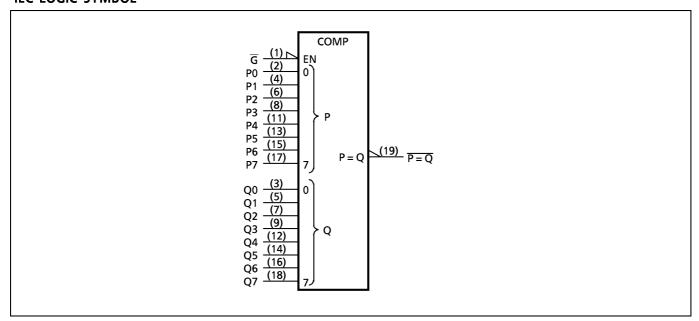
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SYSTEM DIAGRAM



IEC LOGIC SYMBOL



ABSOLUTE MAXIMUM RATINGS

| PARAMETER | SYMBOL | VALUE | UNIT |
|------------------------------------|------------------|----------------------------|------|
| | | -0.5~7.0 | V |
| Supply Voltage Range | V_{CC} | -0.5~7.0 | V |
| DC Input Voltage | V _{IN} | $-0.5 \sim V_{CC} + 0.5$ | V |
| DC Output Voltage | V _{OUT} | −0.5~V _{CC} + 0.5 | V |
| Input Diode Current | I _{IK} | ± 20 | mA |
| Output Diode Current | I _{OK} | ± 20 | mA |
| DC Output Current | I _{OUT} | ± 25 | mA |
| DC V _{CC} /Ground Current | I _{CC} | ± 50 | mA |
| Power Dissipation | P _D | 500 (DIP)* / 180 (SOP) | mW |
| Storage Temperature | T _{stg} | −65~150 | °C |

^{*500}mW in the range of Ta = $-40^{\circ}\text{C} \sim 65^{\circ}\text{C}$. From Ta = 65°C to 85°C a derating factor of $-10\text{mW}/^{\circ}\text{C}$ should be applied up to 300mW.

RECOMMENDED OPERATING CONDITIONS

| PARAMETER | SYMBOL | VALUE | UNIT |
|--------------------------|---------------------------------|-------------------|-------------|
| Supply Voltage | V _{cc} | 4.5~5.5 | < |
| Input Voltage | V _{IN} | 0~V _{CC} | > |
| Output Voltage | V _{OUT} | 0∼V _{cc} | V |
| Operating Temperature | T _{opr} | −40~85 | °C |
| Input Rise and Fall Time | t _r , t _f | 0~500 | ns |

DC ELECTRICAL CHARACTERISTICS

| PARAMETER SYMBO | | TEST CONDITION | | V _{CC} | Ta = 25°C | | | Ta = -4 | UNIT | |
|-------------------------------|-----------------|--|--|------------------|-----------|------|-------|---------|-------|---------|
| PARAIVIETER | STIVIBUL | TEST CONDITION | | (v) | MIN. | TYP. | MAX. | MIN. | MAX. | OINII |
| High - Level Input Voltage | V _{IH} | | | 4.5 \$ 5.5 | 2.0 | 1 | ı | 2.0 | 1 | V |
| Low - Level Input Voltage | VIL | | | 4.5 \$ 5.5 | - | 1 | 0.8 | _ | 0.8 | ٧ |
| High - Level | V _{OH} | V _{I N} = | $I_{OH} = -20 \mu A$ | 4.5 | 4.4 | 4.5 | ı | 4.4 | _ | V |
| Output Voltage | • ОН | V _{IH} or V _{IL} | $I_{OH} = -4 \text{ mA}$ | 4.5 | 4.18 | 4.31 | | 4.13 | _ | V |
| Low - Level | V _{OL} | V _{IN} = | $I_{OL} = 20 \mu A$ | 4.5 | 1 | 0.0 | 0.1 | _ | 0.1 | v |
| Output Voltage | VOL | V _{IH} or V _{IL} | $I_{OL} = 4 \text{ mA}$ | 4.5 | 1 | 0.17 | 0.26 | _ | 0.33 | V |
| Input Leakage Current | I _{IN} | $V_{IN} = V_{CC}$ or GND | | 5.5 | - | 1 | ± 0.1 | _ | ± 1.0 | |
| Quiescent Supply | | $V_{IN} = V_{CC}$ or GND | | 5.5 | ı | | 4.0 | _ | 40.0 | μ A |
| Current | I _C | PER INPUT:V _{IN} OTHER INPUT | _N = 0.5V or 2.4V :V _{CC} or GND | 5.5 | _ | _ | 2.0 | _ | 2.9 | mA |

AC ELECTRICAL CHARACTERISTICS ($C_L = 15pF$, $V_{CC} = 5V$, $Ta = 25^{\circ}C$, Input $t_r = t_f = 6ns$)

| | | | • | | | |
|---|--------------------------------------|----------------|------|------|------|------|
| PARAMETER | SYMBOL | TEST CONDITION | MIN. | TYP. | MAX. | UNIT |
| Output Transition Time | t _{TLH} t _{THL} | | _ | 6 | 12 | |
| Propagation Delay Time (Pn, Qn $\overline{P} = \overline{Q}$) | t _{pLH} t _{pHL} | | _ | 17 | 27 | ns |
| Propagation Delay Time $(\overline{G} - \overline{P} = \overline{Q})$ | t _{pLH} t _{pHL} | | _ | 12 | 19 | |

AC ELECTRICAL CHARACTERISTICS ($C_L = 50pF$, Input $t_r = t_f = 6ns$)

| PARAMETER | SYMBOL | TEST CONDITION | _ | Ta = 25°C | | | Ta = -4 | UNIT | |
|---|---|----------------|-------------|-----------|----------|----------|---------|----------|----|
| PARAIVIETER | STIVIBOL | | $V_{CC}(V)$ | MIN. | TYP. | MAX. | MIN. | MAX. | |
| Output Transition Time | t _{TLH} t _{THL} | | 4.5 5.5 | | 8 7 | 15 13 | _ | 19 16 | |
| Propagation Delay Time (Pn, Qn $\overline{P} = \overline{Q}$) | t _{pLH} t _{pHL} | | 4.5 5.5 | _ | 21 18 | 32 29 | _ | 40 36 | ns |
| Propagation Delay Time $(\overline{G} - \overline{P} = \overline{Q})$ | $egin{array}{c} oldsymbol{t}_{pHL} \end{array}$ | | 4.5 5.5 | _ | 15 13 | 23 21 | _ | 29 26 | |
| Input Capacitance | C _{IN} | | | _ | 5 | 10 | _ | 10 | ne |
| Power Dissipation Capacitance | C _{PD} (1) | | | _ | 32 | _ | _ | _ | pF |

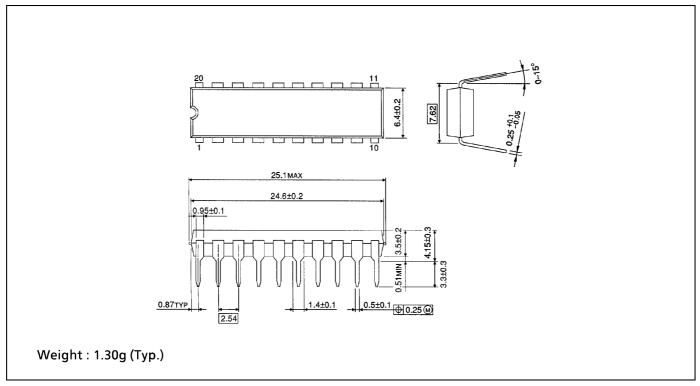
Note (1) C_{PD} is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load.

Average operating current can be obtained by the equation:

 I_{CC} (opr) = $C_{PD} \cdot V_{CC} \cdot f_{IN} + I_{CC}$

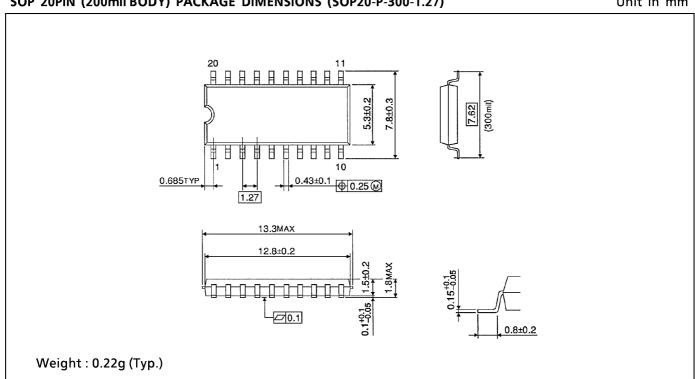
DIP 20PIN PACKAGE DIMENSIONS (DIP20-P-300-2.54A)

Unit in mm



SOP 20PIN (200mil BODY) PACKAGE DIMENSIONS (SOP20-P-300-1.27)

Unit in mm



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